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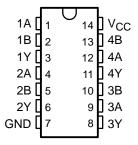
- Operating Range 2-V to 5.5-V V_{CC}
- EPIC[™] (Enhanced-Performance Implanted CMOS) Process
- High Latch-Up Immunity Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

description

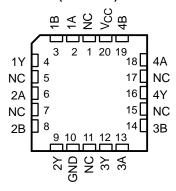
The 'AHC08 are quadruple 2-input positive-AND gates. These devices perform the Boolean function $Y = A \bullet B$ or $Y = \overline{A} + \overline{B}$ in positive logic.

The SN54AHC08 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AHC08 is characterized for operation from -40°C to 85°C.

SN54AHC08 . . . J OR W PACKAGE SN74AHC08 . . . D, DB, N, OR PW PACKAGE (TOP VIEW)



SN54AHC08 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

FUNCTION TABLE (each gate)

INP	UTS	OUTPUT
Α	В	Υ
Н	Н	Н
L	X	L
Х	L	L



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

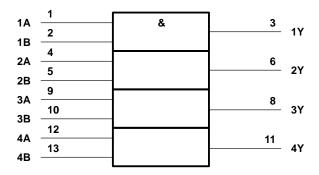
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SN54AHC08, SN74AHC08 QUADRUPLE 2-INPUT POSITIVE-AND GATES

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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, J, N, PW, and W packages.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input voltage range, V _I (see Note 1)		0.5 V to 7 V
Output voltage range, VO (see Note 1)		$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$)		–20 mA
Output clamp current, IOK (VO < 0 or VO > VCO	C)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})		±25 mA
Continuous current through V _{CC} or GND		±50 mA
Package thermal impedance, θ_{JA} (see Note 2):	: D package	127°C/W
	DB package	158°C/W
	N package	78°C/W
	PW package	170°C/W
Storage temperature range, T _{stg}		–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stressratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.



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recommended operating conditions (see Note 3)

			SN54A	HC08	SN74A	HC08	UNIT
			MIN	MAX	MIN	MAX	UNII
Vcc	Supply voltage		2	5.5	2	5.5	V
		V _{CC} = 2 V	1.5		1.5		
VIН	High-level input voltage	V _{CC} = 3 V	2.1		2.1		V
		V _{CC} = 5.5 V	3.85		3.85		
		V _{CC} = 2 V		0.5		0.5	
VIL	Low-level input voltage	V _{CC} = 3 V		0.9		0.9	٧
		V _{CC} = 5.5 V		1.65		1.65	
٧ı	Input voltage		0	5.5	0	5.5	V
٧o	Output voltage		0	VCC	0	VCC	V
		V _{CC} = 2 V		-50		-50	μΑ
IOH	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4		-4	mA
		$V_{CC} = 5 V \pm 0.5 V$		-8		-8	IIIA
		V _{CC} = 2 V		50		50	μΑ
loL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4		4	mA
		$V_{CC} = 5 V \pm 0.5 V$		8		8	IIIA
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100		100	ns/V
ΔυΔν	Input transition rise or fall rate $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$			20		20	TIS/V
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	Vaa	T,	\ = 25°C	;	SN54A	HC08	SN74A	HC08	LINUT
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
		2 V	1.9	2		1.9		1.9		
	I _{OH} = -50 μA	3 V	2.9	3		2.9		2.9		
V _{OH}		4.5 V	4.4	4.5		4.4		4.4		V
	I _{OH} = -4 mA	3 V	2.58			2.48		2.48		
	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8		
		2 V			0.1		0.1		0.1	
	I _{OL} = 50 μA	3 V			0.1		0.1		0.1	
V _{OL}		4.5 V			0.1		0.1		0.1	V
	I _{OL} = 4 mA	3 V			0.36		0.5		0.44	
	I _{OL} = 8 mA	4.5 V			0.36		0.5		0.44	
I _I A or B inputs	V _I = V _{CC} or GND	5.5 V			±0.1		±1		±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			2		20		20	μΑ
C _i	$V_I = V_{CC}$ or GND	5 V		4	10				10	pF

SN54AHC08, SN74AHC08 QUADRUPLE 2-INPUT POSITIVE-AND GATES

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM		TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			MIN	BAAV.	UNIT
	(1141 01)	(0011 01)	OAI AOITANOE	MIN	TYP	MAX	IVIIN	MAX		
^t PLH*	A or B	V	C _L = 15 pF		6.2	8.8	1	10.5	ns	
^t PHL*	AOIB	1		6.2	8.8	1	10.5	115		
^t PLH	A or B	~	C: - 50 pE		8.7	12.3	1	14	nc	
^t PHL	AUID	ſ	C _L = 50 pF		8.7	12.3	1	14	ns	

^{*} On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

switching characteristics over recommended operating free-air temperature range, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted) (see Figure 1)

					SN	74AHC	08					
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T,	λ = 25°C	;	MIN	MAX	UNIT			
	(01)	(0011 01)	5/11/1011/11/0 <u>2</u>	MIN	TYP	MAX	IVIIIN	WAX				
^t PLH	A or B	V	V	C _I = 15 pF		6.2	8.8	1	10.5	no		
t _{PHL}	AUID	ı	•	· ·	ı	ι		6.2	8.8	1	10.5	ns
tpLH	A or B		C: = 50 pE		8.7	12.3	1	14	ns			
tPHL	AOIB		C _L = 50 pF		8.7	12.3	1	14	115			

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER										
	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			MIN	MAX	UNIT	
	(01)			MIN	TYP	MAX	IVIIIV	IVIAA		
^t PLH*	A or B	V	C _L = 15 pF		4.3	5.9	1	7	20	
^t PHL*	AUIB	ī	OL = 13 pr		4.3	5.9	1	7	ns	
^t PLH	A or B	V	C: _ 50 pF		5.8	7.9	1	9	20	
^t PHL	AUID	Y	Y CL	C _L = 50 pF		5.8	7.9	1	9	ns

^{*} On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

switching characteristics over recommended operating free-air temperature range, $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$ (unless otherwise noted) (see Figure 1)

				SN74AHC													
PARAMETER	FROM (INPUT)		LOAD CAPACITANCE	T _A = 25°C			MIN	MAX	UNIT								
	(01)	(0011 01)	OAI AOITAIGE	MIN	TYP	MAX	IVIIIV	WAX									
^t PLH	A or B	V	C _L = 15 pF		4.3	5.9	1	7	20								
^t PHL	AUIB	T		1	ı	'	·	'	, I	ı	ι		4.3	5.9	1	7	ns
^t PLH	A or B	V	C: - 50 pF		5.8	7.9	1	9	50								
^t PHL	AUB	Ĭ	C _L = 50 pF		5.8	7.9	1	9	ns								

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noise characteristics, $V_{CC} = 5 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 4)

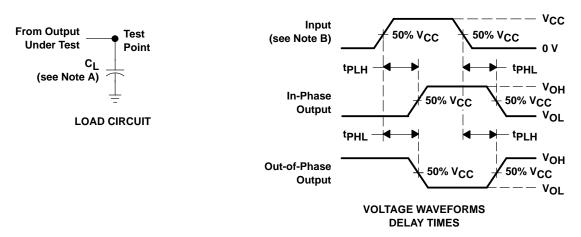
	PARAMETER	SN74A	HC08	UNIT
	PARAMETER	MIN	MAX	UNII
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.8	V
V _{OL(V)}	Quiet output, minimum dynamic VOL		-0.8	V
VIH(D)	High-level dynamic input voltage	3.5		V
V _{IL(D)}	Low-level dynamic input voltage		1.5	V

NOTE 4: Characteristics are determined during product characterization and ensured by design for surface-mount packages only.

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CO	ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	18	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_f = 3 ns, t_f = 3 ns.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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